

1. General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection in a DSN0603-2 (SOD962-2) leadless ultra small Surface-Mounted Device (SMD) package.

2. Features and benefits

- Average forward current I_{F(AV)} ≤ 0.5 A
- Reverse voltage V_R ≤ 30 V
- Low forward voltage typ. V_F = 250 mV
- Low reverse current typ. I_R = 4 μA
- Ultra small and leadless SMD package
- Package height typ. 0.3 mm

3. Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Low power consumption applications
- Ultra high-speed switching
- LED backlight for mobile application

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; T _{amb} ≤ 105 °C; square wave	[1]	-	-	0.5	A
		δ = 0.5; f = 20 kHz; T _{sp} ≤ 140 °C; square wave		-	-	0.5	A
V _R	reverse voltage	T _j = 25 °C		-	-	30	V
V _F	forward voltage	I_F = 10 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C		-	250	[tbd]	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C		-	4	[tbd]	μA
t _{rr}	reverse recovery time	I _R = 500 mA; I _F = 500 mA; I _{R(meas)} = 100 mA; T _j = 25 °C		-	[tbd]	-	ns





30 V, 0.5 A low VF MEGA Schottky barrier rectifier

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode[1]		1 🛃 2
2	А	anode		sym001
			Transparent top view	
			DSN0603-2 (SOD962-2)	

[1] The marking bar indicates the cathode.

6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
PMEG3005AESF	DSN0603-2	Leadless ultra small package; 2 terminals; body 0.6 x 0.3 x 0.3 mm	SOD962-2

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMEG3005AESF	8

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage	T _j = 25 °C		-	30	V
l _F	forward current	T _{sp} ≤ 135 °C		-	0.7	А
I _{F(AV)}	average forward current	δ = 0.5; f = 20 kHz; T _{amb} ≤ 105 °C; square wave	[1]	-	0.5	Α
		δ = 0.5; f = 20 kHz; T _{sp} ≤ 140 °C; square wave		-	0.5	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.25$		-	1.5	А
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	4	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	325	mW
			[3]	-	525	mW
			[1]	-	950	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

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Thermal characteristics 9.

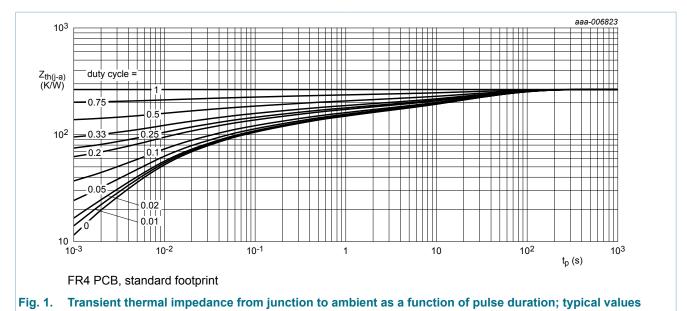
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	[1][2]	-	-	310	K/W
	from junction to ambient		[1][3]	-	-	190	K/W
	ambient		[1][4]	-	-	105	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	40	K/W

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [2]

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for anode and cathode 1 cm² each.

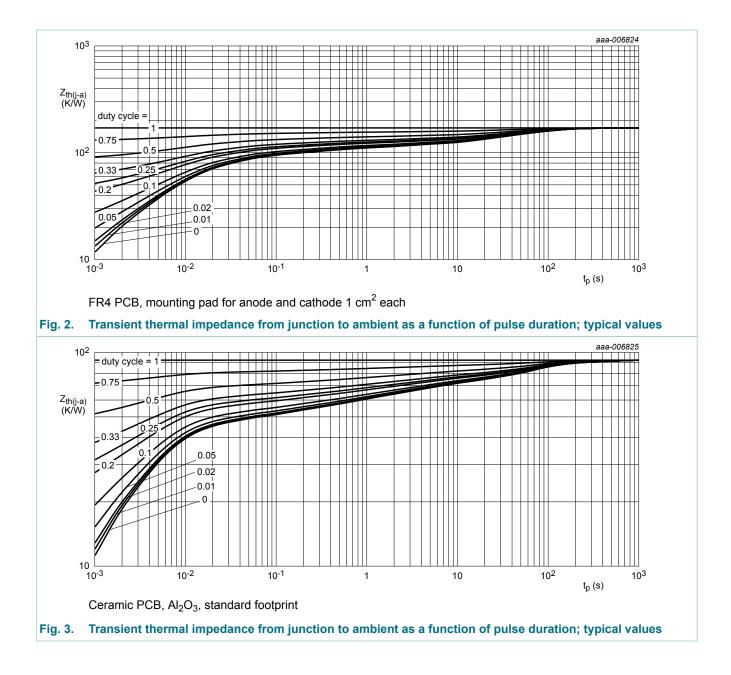
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.



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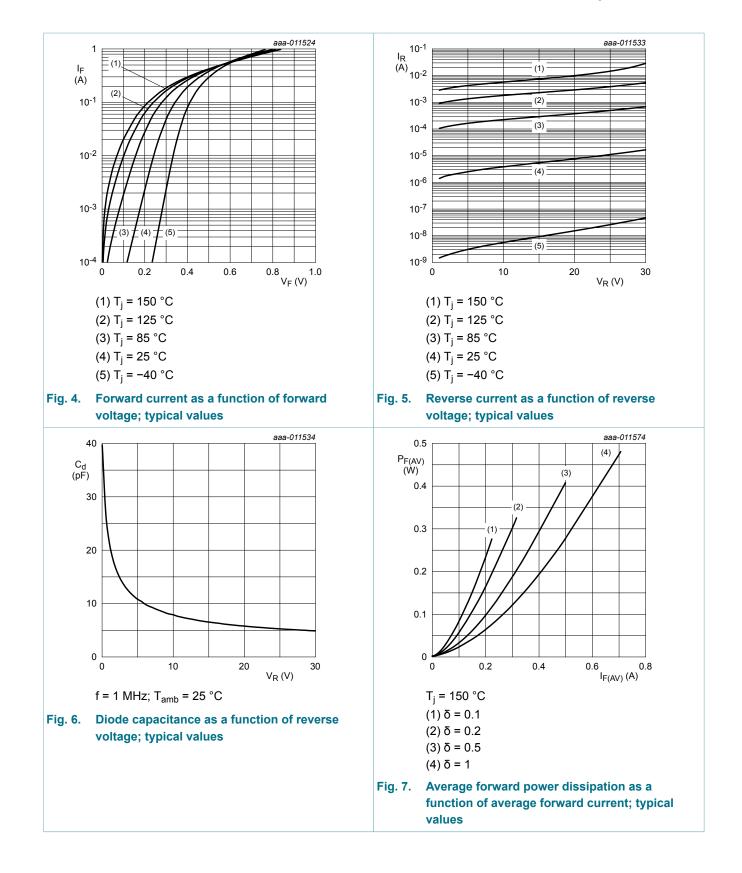


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10. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VF	forward voltage	I_F = 0.1 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	120	[tbd]	mV
		I _F = 1 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	180	[tbd]	mV
		I _F = 10 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _j = 25 °C	-	250	[tbd]	mV
		I _F = 100 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _j = 25 °C	-	350	[tbd]	mV
		I _F = 200 mA; pulsed; t _p ≤ 300 μs; $\delta \le 0.02$; T _j = 25 °C	-	405	[tbd]	mV
		I_F = 500 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _j = 25 °C	-	560	[tbd]	mV
I _R	reverse current	V _R = 10 V; T _j = 25 °C	-	4	[tbd]	μA
		V _R = 30 V; T _j = 25 °C	-	20	[tbd]	μA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	22	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	8	-	pF
t _{rr}	reverse recovery time	I _F = 500 mA; I _R = 500 mA; I _{R(meas)} = 100 mA; T _j = 25 °C	-	[tbd]	-	ns

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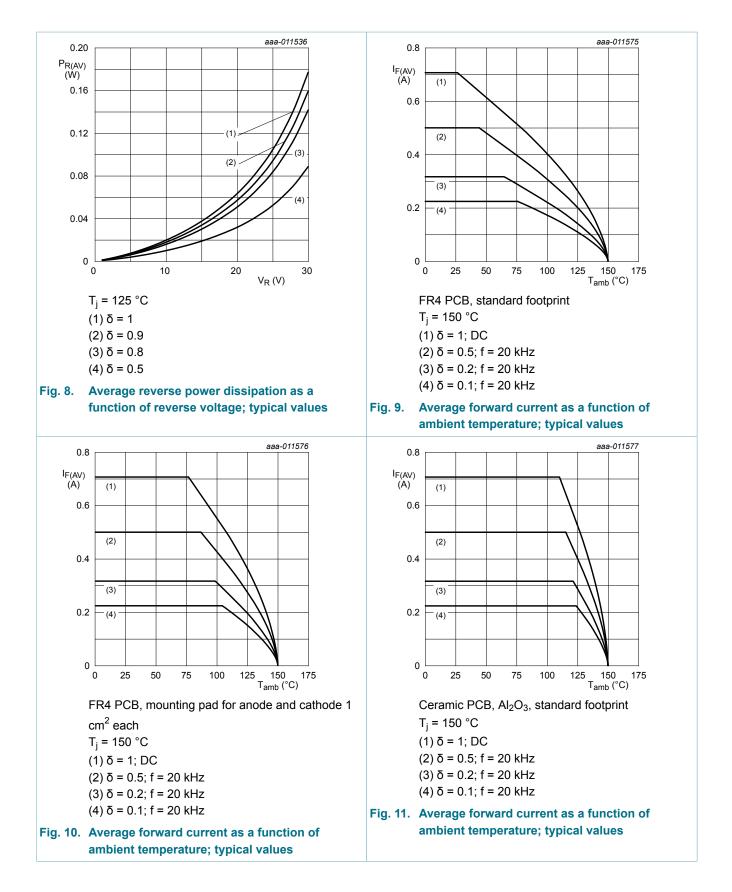
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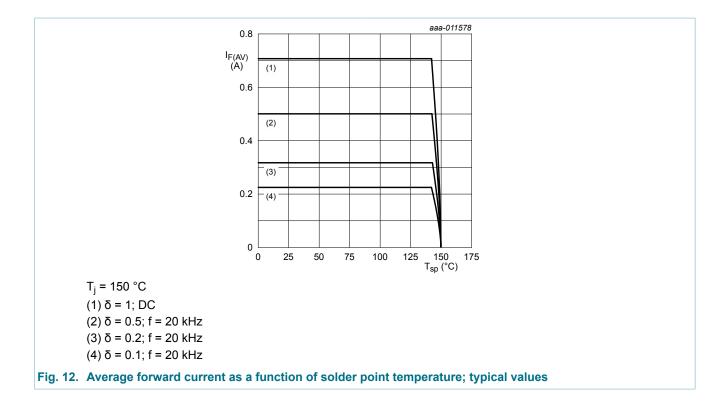
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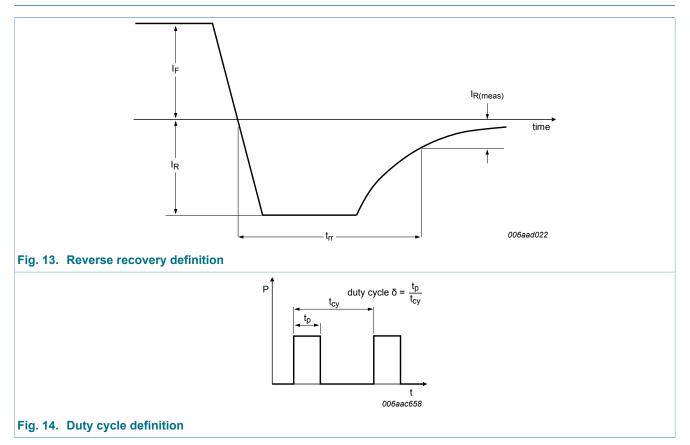
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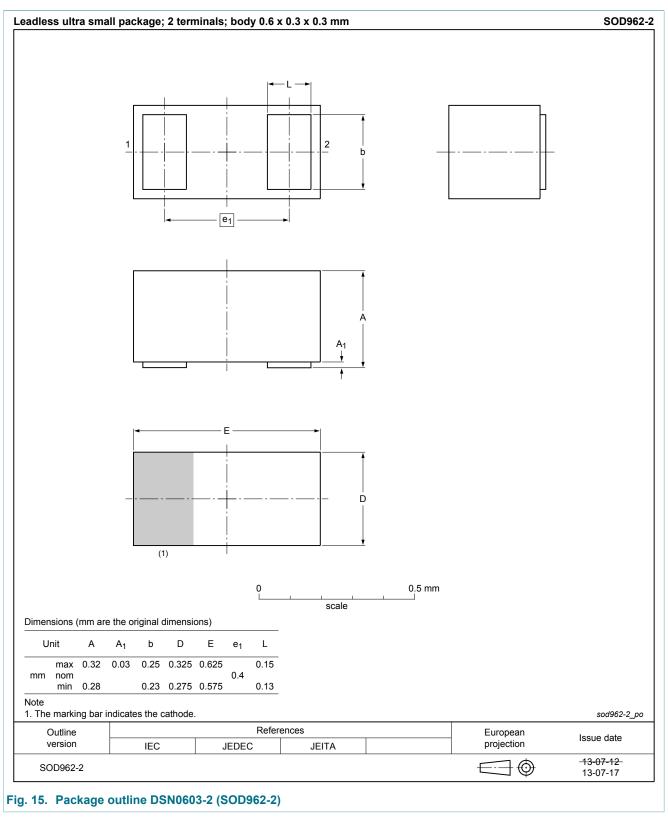
11. Test information



The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

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12. Package outline



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Preliminary data sheet

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13. Soldering

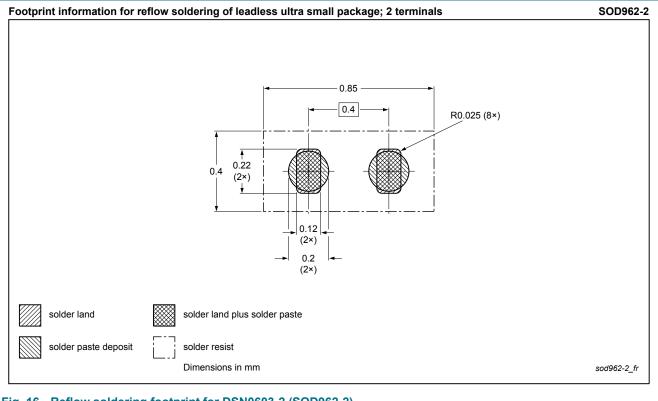


Fig. 16. Reflow soldering footprint for DSN0603-2 (SOD962-2)

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14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMEG3005AESF v.1	20140505	Preliminary data sheet	-	-			

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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